The ‘Generalized Skettrup Model’ and Matsubara Statistics

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The ‘Generalized Skettrup Model’ (GSM) [1] links features of near-band gap and intra-gap electronic as well as corresponding optical spectra of polycrystalline and spatially non-homogeneous amorphous semiconductors and insulators to probabilities of fluctuations in an energy of the individual quasi-particle, number of quasi-particles in a quantum grand canonical ensemble (QGCE) of confined acoustic phonons with static plane-wave basis (pure states), and in their aggregate energy. Features of the GSM [1] are discussed herein in comparison to those of quantum statistics pioneered by famous Japanese physicist T. Matsubara [2], which is based essentially on two-points ‘Green Function’ (GF) formalism, and takes into account fluctuations in temperature of QGCE. The GSM [1] might be ultimately treated as a ‘conservative’ (and essentially static) counterpart of the generic Matsubara statistics for the specific case of ensemble of acoustic phonons confined within micrometer- and sub-micrometer-sized non-homogeneities (crystallites) of polycrystalline and spatially non-homogeneous amorphous semiconductors and insulators. However, unambiguous links among spectral characteristics of the GSM and Matsubara GF might be established for equilibrated phononic ensembles with static and/or dynamic plane-wave basis. Moreover, original scope of the GSM might be expanded further based on the fundamental ideas, pioneered by T. Matsubara.

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1. Introduction

The Generalized Skettrup Model (GSM) depicted in the second chapter of ref. [1] (see also references therein) is essentially based on evaluation of probabilities of fluctuations in an energy of pure state(s) of individual acoustic phonons, their aggregate energy and (generally rational) number of quasi-particles of the (quantum) grand canonical ensemble (QGCE), corresponding to many-particle phononic excitations with static (time-independent) plane-wave basis (pure states) in polycrystalline and/or spatially non-homogeneous amorphous semiconductors and insulators. In particular, within the GSM framework, those fluctuation probabilities are customarily evaluated via an integration (averaging) over available (at the given aggregate energy) mixed quantum states of ensemble of Debye’s acoustic phonons and appropriate number of those quasi-particles [1]. Furthermore, the GSM implies that those fluctuations in the ensemble of confined longitudinal acoustic phonons with the static plane-wave basis (microstates) are linked intimately to energy fluctuations in an electronic sub-system of a semiconductor (insulator) and eventually to its corresponding optical spectra: relationship between the instantaneous aggregate energies (fluctuation probabilities) of electronic and phononic sub-systems might be established quantitatively either based on semi-empirical electron-phonon coupling parameters or via the ‘deformation potential’ formalism [1].

Thus, aforementioned GSM approach essentially implies that the individual and aggregate energies as well as number of quasi-particles in the phononic ensemble have to be treated as real (generally rational) variables, while temperature of the ensemble is usually treated as a fixed (constant) quantity for the given environmental conditions; i.e., as a parameter of an external ‘thermal reservoir’. In contrast, quantum statistical mechanics pioneered (in particular) by famous Japanese physicist Takeo Matsubara for a quantum ensemble with a time-dependent (dynamic) basis (comprises either electrons (fermions) or phonons (bosons)) [2] is based essentially on properties of ‘equilibrium’ two-points ‘Green Function’ (GF), and treats the temperature of QGCE as a variable complex parameter. This implies that the temperature of the ensemble fluctuates as well – in addition to fluctuations in total number of its quasi-particles and in their individual and aggregate energies for the given QGCE. Furthermore, quantitative parameters of the conventional two-points GF might be evaluated appropriately via substitution of real-time variable of the GF defined in Euclidian space-time continuum with its ‘imaginary time’ counterpart, which is inversely proportional to the temperature of the ensemble [2]. Such treatment becomes essential for interacting systems: condensed matter, dense plasmas, neutron stars etc., where local temperature fluctuations are expected to be considerable or dominant. Herein significances of aforesaid effects are evaluated only for solid crystalline and non-homogeneous amorphous semiconductors and insulators, including nano-structured ones, and discussed in comparison with predictions of the GSM [1].
2. Key Features of Matsubara Statistics

In a thermal equilibrium, averaged (statistical) characteristics of pure or mixed (static and/or dynamic) many-body state(s) of a non-interacting (either fermionic or bosonic) ensemble at the given (absolute) temperature $T$ are routinely evaluated based on the quantum grand canonical density operator, $\rho_D$ [3]:

$$\rho_D = \frac{\exp(-H_0 / k_B T)}{Tr[\exp(-H_0 / k_B T)]},$$  \hspace{1cm} (1)

where $Tr[\exp(-H_0 / k_B T)]$ denotes trace (i.e., sum over its diagonal elements) of the matrix exponential of the weighted ‘thermal’ Hamiltonian matrix ($H_0 / k_B T$), and $k_B$ is the Boltzmann constant. This $\rho_D$ operator is Hermitian, ‘positive definite’ and normalized: $\text{Tr}(\rho_D) = 1$ [3]. Importantly, that Eq.(1) remains valid even for Heisenberg representation of the quantum mechanics, which presumes that wavefunctions (set of basic states) of the system and its Hamiltonian are time-independent (static), while operators do change in time.

An essential generalization of concept of equilibrium statistics for an (bosonic or fermionic) ensemble with a time-dependent (dynamic) basis had been achieved [2] via implementation of a single-particle two-points Matsubara ‘Green Function’ (GF), expressed herein using a coordinate representation [4]:

$$\tilde{G}_M(\vec{r}_1, \tau_1, \vec{r}_2, \tau_2) = \frac{\text{Tr}\{\exp\left[(\mu N - H_0)/(k_B T)\right] T_\tau \left[\Psi_\alpha(\vec{r}_1, \tau_1)\Psi^*_\alpha(\vec{r}_2, \tau_2) N(1/T)\right]\}}{\text{Tr}\{\exp\left[(\mu N - H_0)/(k_B T)\right] N(1/T)\}},$$  \hspace{1cm} (2)

where $\vec{r}_1, \tau_1$ and $\vec{r}_2, \tau_2$ stand for spatial and imaginary time ‘coordinates’ of the first and second points (at where the single particle appears/vanishes) of an appropriate space-time continuum, $N$ is number of particles in the ensemble, $\mu$ is its chemical potential, $\Psi_\alpha(\vec{r}, \tau)$ is an imaginary-time-dependent operator, acting on (time-independent) wavefunction(s) (eigenstates, numerated by their index $\alpha$) of the ensemble, and $\Psi^*_\alpha(\vec{r}, \tau)$ is its complex-conjugate, $T_\tau$ is so-called ‘time-ordering’ operator with respect to the imaginary time, while $N(1/T)$ is a form of ‘density matrix’, defined (based on a generic identity) in ref. [4] as follows:

$$N(1/T) = T_\tau \exp\left[-i\int_0^1 H_{\text{int}}(t) dt\right] = T_\tau \exp\left[-\int_0^1 H_{\text{int}}(\tau) d\tau\right],$$  \hspace{1cm} (3)

where $i = \sqrt{-1}$, $\beta = i t/(k_B T)$, $\tau = it$, and $H_{\text{int}}(t)$ is a (time-dependent) ‘interaction Hamiltonian’ of the ensemble [4]. Thus, Eqs.(2, 3) manifest a two-points generalization (in coordinate representation) of the conventional (‘thermal’) density matrix, as well as density operator, expressed by Eq.(1). In particular, Eq.(1) might be ‘restored’ from Eq.(2) in the ‘equal times’ limit, i.e., at $\tau_1 = \tau_2$. The Eq.(2) is formally compatible with Heisenberg representation of quantum mechanics. An integration over the ‘imaginary time’ in Eq.(3) seemingly yields an ‘interaction representation’ for the statistical ensemble [2–4].

In apparent distinction from the conventional’ GF $\tilde{G}(\vec{r}_1, t_1, \vec{r}_2, t_2)$, the Matsubara’s ‘equilibrium’ two-point GF $\tilde{G}_M(\vec{r}_1, \tau_1, \vec{r}_2, \tau_2)$ specified by Eqs.(2, 3), was established in ref. [2] via substitution of real-time variable $t$ of the conventional GF with its ‘imaginary time’ counterpart $\tau = it$ (i.e., via so-called ‘Wick rotation’), which is also related directly to the inverse temperature, $1/T$, of the ensemble. This idea was apparently inspired by the structure of Minkowski (relativistic) space-time metric, which comprises of imaginary time axis. Formally, the equilibrium GFs, $\tilde{G}(\vec{r}_1, t_1, \vec{r}_2, t_2)$ and $\tilde{G}_M(\vec{r}_1, \tau_1, \vec{r}_2, \tau_2)$ one, depend only on the time difference(s) [3]. Furthermore, in an equilibrium state, the Hamiltonian $H_0$ of the system is expected to be static (time-independent), and fluctuations of the ensemble parameters have to be attributed mainly to its evolution on the imaginary time axis, or fluctuation(s) in its local temperature.

This kind of evolution (fluctuation) might be formally depicted by Eqs.(2, 3), as long as integration in Eq.(3) is fulfilled along the straight line, parallel to the ‘imaginary time’ axis on the complex time plane [2–4]. In such a case, Eq.(3) might be re-formulated in a more compact (and yet generic) form [3]:

$$U(t_0 - \beta, t_0) = \exp\left(i \beta \hat{H}_0\right),$$  \hspace{1cm} (4)

here $U$ denotes an evolution operator, and $t_0$ stands for an ‘origin’ of the real time axis. It is noteworthy, that evolution of the bosonic ensemble is periodic on the imaginary time scale, while evolution of the fermionic ensemble is ‘antiperiodic’ [2–4].
Alternatively, any (temperature-dependent) function in Euclidian space (e.g., phonon eigenfunction, conventional GF, creation and/or annihilation operator, thermal ‘propagator’ etc.) might be expanded readily in an infinite exponential Fourier series over imaginary time with (Matsubara) frequencies $\omega_n$, which are routinely defined for bosonic ensemble based on periodicity conditions of those exponential terms: $\exp(i\omega_0 t) = 1$ for $\omega_0 = 2\pi n$. Consequently, in general, integration over imaginary time in Eq.(3) might be replaced with a (finite) summation over the Matsubara frequencies. However, in apparent contradiction with Eqs.(3, 4), those Matsubara frequencies $\omega_n$ naturally become temperature-dependent, but not affected neither by frequencies of pure states (individual modes) of the phononic ensemble nor by their aggregate energy. In particular, based on the mentioned above periodicity condition, one readily obtains: $\beta\omega_n = 2\pi n$ or $\omega_n = -2\pi i k_B T n$ (n herein is an integer index) [2, 3]. At $T = 1 K$ and $n = -1$, this periodicity condition yields: $\omega_{-1} = 2\pi i k_B T \approx 5.414 \times 10^{-4}$ eV. Higher Matsubara frequencies are just proportional to the $\omega_1$ quantity. Similar Matsubara frequencies might be defined readily as well for a fermionic ensemble [2 – 4]. Thus, fluctuations (and interactions) in either bosonic or fermionic ensemble might be taken into account via appropriate expansion over the imaginary time or frequency domain(s) of the given ensemble.

The original Matsubara’s idea is tremendously fruitful and was further developed and implemented for decades in GF-based formalisms of a finite-temperature quantum statistic of condensed systems [3, 4]. In addition, it was advanced further by T. Matsubara in order to establish diagrammatic perturbation theory for their grand partition functions within framework of the field-theoretical basis [2 – 4]. However, ‘orthodox’ GF and diagrammatic formalisms do not apply to “…Bose systems below points of the Bose condensation…” and ‘…Fermi systems in which superconductivity exists…” [4].

3. ‘Matsubara Correction’ for GSM with Static Plane-wave Basis

The basic feature of the briefly depicted in the previous section Matsubara’s generalization of the fluctuation concept might be incorporated naturally into the framework of essentially static GSM [1]. Indeed, basic equation of (isotropic version) of the GSM comprises of the Gibbs (Boltzmann) term, total number of available static mixed states of QGCE of Debye acoustic phonons with the plane-wave functions (pure states) as well as its ‘normalizing’ factor, $\Gamma(M + 1)$, and a ‘partition function’, $Z_M$ [1]:

$$W_D(E_T) \cong \exp\left(-\frac{E_T}{k_B T}\right) \int_{M_0}^{M} \frac{1}{\Gamma(M + 1)(Z_M)^{r_2}} \frac{2L_x L_y F(L_x, L_y, L_z) E_T^{r_1}}{M^{r_2}(c_i)^2} dM, \quad (5)$$

where $W_D(E_T)$ denotes probability density of finding of the ensemble of confined (within a parallelepiped crystallite, column, cone) Debye acoustic phonons in a mixed state with its aggregate energy of $E_T$, $\Gamma(M + 1)$ is Euler’s Gamma-function [5], $k_B$ is the Planck’s constant, $c_i$ is longitudinal sound velocity, $L_x, L_y, L_z$ are lengths of the (orthogonal) ribs of parallelepiped phonon confinement volume, while the dimensionless function $F(L_x, L_y, L_z)$ depends solely on ratios of the $L_x, L_y$ and $L_z$ lengths; see also Eq.(26a) in ref. [1]. Integration in Eq.(5) is expected to be carried out over the appropriate range of (generally rational) number $M$ of acoustic phonons in the ensemble (this integration range is restricted by the $M_0$ and $M_0$ limits), while dimensionless (and rational in general) model parameters $r_1$ and $r_2$ are typically varying in the following ranges: $0.5 \leq r_1 \leq 2; \quad 0.5 \leq r_2 \leq 1$ [1]. Furthermore, $M_0 = (E_T/k_B \theta_0)_{\text{el/2}}$ with Debye energy of the solid equals to $k_B \theta_0$ and Debye temperature of $\theta_0$, while $M_{\text{max}} = (E_T/E_{\text{max}})_{\text{el/2}}$, with a low limit, $E_{\text{max}}$, of the aggregate energy of the ensemble of bosonic phonons, imposed by presence of morphology (non-homogeneties) in studied (isotropic but spatially non-homogeneous) polycrystalline or amorphous semiconductor (insulator), and defined by Eq.(18B) in ref. [1] for such a case. Importantly that the GSM framework in general and Eq.(5) comply naturally with Heisenberg’s uncertainty principle.

In spite of significant differences in notations, structures of Eq.(2, 5) exhibit apparent similarities, in particular, at $\mu = 0$ and $M = 1$. Furthermore, close formal interrelations among those equations might be established readily for a specific case of the ensemble of Debye acoustic phonons with the plane-wave basis and ‘classical’ linear dispersion: $\omega_n \equiv c q$ (here $\omega_0$ corresponds to the quasi-wave vector $q$).

Indeed, first of all, unambiguous interrelations between equilibrium two-points $G(r_1, t_1, r_2, t_2)$ function and the ‘conservative’ Eq.(5) really do exist in such a case due to the following well-known identities [5]:

$$\exp[-i \mathbf{q}(t-t')] \exp[-i \mathbf{q}(\mathbf{r}' - \mathbf{r})] = \delta(t-t') + \delta(\mathbf{r}' - \mathbf{r}) \equiv \delta(t-t') + \delta(\mathbf{r}' - \mathbf{r}). \quad (6)$$

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Thus, based on those identities, eigenfunctions of the equilibrium ‘conventional’ GF, defined at two points \([\mathbf{r}, t], (\mathbf{r}', t')\) of Euclidian space-time continuum are linked directly to a number of single-point (with coordinates of \([\mathbf{r}, t], (\mathbf{r}', t')\)) poles (states) of the plane wave with the angular frequency \(\omega_\mathbf{q}\), propagating within the continuum. On the other hand, number of single-phonon states in integrand of Eq.\((5)\) at \(M = 1\) equals to number of poles of static plane-wave basis of Debye phonons; i.e., only right-hand terms in all equalities expressed by the Eq.\((6)\) have to be taken into account in such a case. However, quantitative interrelations among eigenfunctions of Eq.\((5)\) and those of Matsubara GF, defined by Eq.\((2)\) are not so straightforward, see next section for details. Furthermore, an appropriate sum (over all available indexes \(\alpha\)) of the products \([\Psi_+^\alpha(\mathbf{r}, t) - \Psi_-^\alpha(\mathbf{r}, t)]\) of the ‘one-body’ and ‘equal-times’ annihilation and creation operators (acting on the given set of ground (basis) plane-wave-functions) would yield a total density of Debye phonons in Eq.\((2)\) at the particular point of Euclidian space \([4, 6, 7]\). Consequently, the total number of such phonons confined within the parallelepiped volume of \(V_p = \mathbf{L}_x \mathbf{L}_y \mathbf{L}_z\) has to be defined by integration over the aforementioned phonon density, and over the whole volume, \(V_p\). Moreover, since Eq.\((2)\) is formulated within the ‘second quantization’ framework \([4, 6, 7]\), actual spectrum of excitations of the ‘ground’ states of the (bosonic or fermionic) ensemble is routinely described based on spectral characteristics of its individual quasi-particles and appropriate occupation factor for the single-particle (ground) states; see also next section for an example. Thus, implementation of the ‘second quantization’ approach and GF formalism to an ensemble of bosons or fermions typically yields scalar (though generally time-dependent) parameters of the ensemble (e.g., average total number of particles in the ensemble, their average aggregate energy etc.), even though its basis wave-functions may contain vital information on direction of their spatial propagation and angular frequency, morphological and anisotropic effects in crystalline lattice, etc.

In contrast, the integrand term located within the square brackets of Eq.\((5)\) is linked directly to parameters of the static plane-wave-functions (pure states) of the ensemble of (longitudinal) Debye acoustic phonons, and retains essentially the long-range (e.g., anisotropic and/or coherent) effects, ‘inherited’ from those plane-wave-functions; see, in particular, Eq.\((2b)\) in ref. \([1]\). Moreover, the number of acoustic phonons is introduced explicitly as a (generally rational) parameter \(M\) of the integrand term in Eq.\((5)\). However, this GSM parameter rather characterize number of quasi-particles in a coherent (i.e., with the same \(\mathbf{q}\) quantity for all its components) and/or excited (or mixed – with non-equal \(\mathbf{q}\) quantities of its components) state of acoustic phonons, than in their ground states (though \(M = 1\) formally matches to the ground state). On the other hand, in apparent similarity with ‘second quantization’ approach – the integrand term located within square brackets of Eq.\((5)\) is defined merely based on the (idealized) single-particle spectrum of (isotropic) Debye acoustic phonon and its first Brillouin Zone (BZ); this similarity is also accomplished by appropriate low integration limit in the Eq.\((5)\) \([1]\). It is noteworthy, that the ‘second quantization’ and Matsubara GF formalisms also allow one to incorporate bosonic coherent states with the plane-wave basis: e.g., ‘normalized’ Klauder’s state: \(\sim (N_C!)^{-1/2} \exp(-i\mathbf{q}\cdot\mathbf{r})\) \([6, 7]\); here \(N_C\) is an integer, while \(\mathbf{q}_c\) is its quasi-wave-vector. Notably, that its squared ‘normalizing’ coefficient \((1/N_C!)\) formally coincides with the \(\Gamma(M+1)\) term in Eq.\((5)\) at \(M = N_C\). However, the \(\mathbf{q}_c\) vector of Klauder’s phononic coherent state routinely exceeds edge of the first phononic BZ. This implies that the \(\mathbf{q}_c\) parameter is ‘ill-defined’ for the phononic states, and such phononic states could not be treated as pure states (microstates) of the ensemble of (longitudinal) acoustic phonons; see also next section for further discussion.

The only term, which appears in the Eq.\((2)\), but apparently absent in Eq.\((5)\) – is the ‘density matrix’ \(\mathcal{N}(1/T)\), defined by the Eq.\((3)\) in the previous section. However, based on the fundamental idea, pioneered by T. Matsubara \([2]\), an appropriate counterpart of the \(\mathcal{N}(1/T)\) term might be introduced readily for the Eq.\((5)\). Indeed, formally, the given scalar \(E_T\) quantity in the exponential term of Eq.\((5)\) might be treated as particular case of a (single-valued) equilibrium (static) Hamiltonian. However, the \(E_T\) quantity apparently comprises of both the sum of ‘self-energies’ of the ensemble of the confined acoustic phonons, as well as a contribution caused by their interactions, while the ‘density matrix’ \(\mathcal{N}(1/T)\) defined by Eq.\((3)\) is based entirely on an ‘interaction Hamiltonian’ \([4]\). Nonetheless, two aforementioned contributions to the \(E_T\) term in Eq.\((5)\) might be separated readily within the GSM framework. Indeed, at the given energy of acoustic phonon, \(\hbar\omega\), the aggregate ‘self-energy’ of the sub-set of \(M\) such equivalent acoustic phonons in the ensemble is just \(E_T^S = E_T = M \cdot \hbar \omega\), while an actual number of such phonons in the ensemble is usually smaller due to presence of the model parameter \(r_1\) \((0.5 \leq r_1 \leq 2.0)\), and equals just to \(M^{(1/2)}\), see terms in square brackets in integrand of Eq.\((5)\) above. Thus, the difference, \(E_T - \hbar \omega \cdot M^{(1/2)} = \hbar \omega [1 - M^{(1/2) - 1}]\), defines the effective interaction energy, \(E_{int}\), for the given sub-set (comprising of \(M^{(1/2)}\) equivalent acoustic phonons) of the ensemble, see Fig.\((1a)\). Now, the ‘normalized’ interaction energy, \(E_{int}^{norm}\), of GSM at the given \(E_T\) and \(M\) quantities might be introduced via the equation: \(E_{int}^{norm} = E_T [1 - M^{(1/2) - 1}] / M;\)
herein it is counted per single phonon. Consecutive integration (over the M0(E_T, r1) ≤ M ≤ M_{max}(E_T, r1) range, see Fig. 1(a) of such ‘normalized’ interaction energy and it additional ‘normalization by the \([E(T)/M])dM\) integral (which is also taken over the M0(E_T, r1) ≤ M ≤ M_{max}(E_T, r1) range) eventually yields:

\[
E_{\text{avr}} = E_T \left[ 1 - \frac{\left(M_{\text{max}}\right)^{(r1/2 - 1)} - \left(M_0\right)^{(r1/2 - 1)}}{(r1/2 - 1) \ln \left(\frac{M_{\text{max}}}{M_0}\right)} \right].
\]  

(7)

The Eq.(7) is apparently non-linear in general, though yields: \(E_{\text{avr}} \rightarrow 0\) at \(r1 \rightarrow 2\). Behavior of the \(E_{\text{avr}}(E_T)\) dependencies obtained based on Eq.(7) at different \(r1\) quantities is illustrated in Fig.1(b) for a specific case of <100>-oriented polycrystalline diamond with the crystallite sizes of \(L_x = L_y = L_z = 1.0\ \mu m\).

Based on simulation results revealed in Fig.1(a) and 1(b), both \(E_{\text{int}}\) and \(E_{\text{avr}}(E_T)\) quantities of the ensemble of acoustic phonons confined in the polycrystalline diamond depend non-monotonically on the GSM parameter, \(r1\) (with apparent maximum at \(r1 = 1.0\)). In particular, the \(E_{\text{avl}}(E_T)/E_T\) fraction equals exactly to zero at \(r1 = 2.0\), but becomes of 0.84386±0.0143 at \(r1 = 1.0\), Fig.1(b). In other words, the \(E_T\) quantity of this ensemble is almost entirely composed of ‘self-energies’ of acoustic phonons at \(r1 \rightarrow 2.0\), while contribution from phonon-phonon interactions comprises of ~84.4% of the \(E_T\) term at \(r1 = 1.0\).

In contrast to the ‘conventional’ (and infinite) set of Matsubara frequencies customarily defined based on periodicity conditions of the exponential term(s) in the Fourier expansion of an Euclidian propagator \([2 - 4]\) (see also end of the previous section), the dimensionless (and always finite) \(\Theta_{\text{M}}(E_T, T)\) function might be introduced based on a physically meaningful number of poles of the exponential term in Eq.(5), which is apparently affected both by the interaction component of its total Hamiltonian (Fig. 1(a), (b)), as well as by its temperature, see Fig. 2(a). Indeed, \(|\beta| = 1/k_BT \simeq 11605\ eV^{-1}\) at \(T = 1\ K\), while its dimensionless counterpart reads: \(|\beta| = |E_{\text{avl}}(E_T)/k_BT| \simeq 11605\) at \(E_{\text{avl}}(E_T) = 1\ eV\). Furthermore, now the (dimensional and dimensionless) Matsubara frequencies might be defined as follows: \(\omega_0 = 2 \pi / k_BT\) n \([2, 3]\) and \(\omega_\beta = (2 \pi / k_BT) / E_{\text{avl}}(E_T)\) (respectively). It is noteworthy, that poles of the exponential term in Eq.(5) as well as just defined above Matsubara frequencies are always located on the imaginary axes of the appropriate complex plane, see Fig. 2(a), (b).

Thus, the physically meaningful number of those poles might be evaluated based on an idea formalized by Eq.(3), where the limited integration range of \([0, \beta]\) is implemented. Consequently, the ‘Matsubara’ correction function \(\Theta_{\text{M}}(E_T, T)\) to Eq.(5) – the counterpart of the \(\mathcal{N}(1/T)\) term – might be introduced based on the meaningful number of the poles of its exponential term, emerged in the complex time domain:
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\[ \Theta_M \left( E_T, T \right) = \exp \left[ -\frac{\beta}{\hbar} E_{\text{int}}^{\text{avr}}(E_T) d \tau \right] = \text{Int} \left[ \frac{E_{\text{int}}^{\text{avr}}(E_T)}{2 \pi k_B T} \right] + 1, \quad (8) \]

here \( \text{Int} \) denotes a function, which returns the integer part of its rational argument, and with the unity term in right-hand side yields the total integer number of poles, located within the imaginary integration range of \([0, \beta]\); while the \( E_{\text{int}}^{\text{avr}}(E_T) \) function ‘embedded’ in the latter equation is defined by Eq.(7) above.

FIG. 2 (a), (b) (color online). Schematic illustration of (a) periodic behavior of the inverse exponential term in Eq.(5) (comprises herein of only ‘interaction’ component of its total Hamiltonian!) on the complex plane with two its zeros located on the imaginary axis, and (b) the Matsubara integration contour (dashed curve). The black dots in figure (b) are located entirely on the imaginary frequency axis and indicate positions of bosonic Matsubara frequencies on the complex frequency plane. See also figure (a) and main text for more details.

Spectral and temperature dependencies of the \( \Theta_M(E_T, T) \) function, defined by Eqs.(7, 8) are illustrated in Fig. 3(a), (b) for a case of \( r_1 = 1 \), and \(<100>-oriented polycrystalline diamond with \( L_x = L_y = L_z = 1.0 \) μm.

FIG. 3 (a), (b) (color online). Effects of (a) the absolute temperature \( T \) and (b) aggregate energy \( E_T \) of the phonon ensemble on the \( \Theta_M(E_T, T) \) function, defined by Eqs.(7, 8) at \( r_1 = 1.0 \) for a case of \(<100>-oriented polycrystalline diamond with \( L_x = L_y = L_z = 1.0 \) μm. The plotted curves are eventually obtained via replacement of the \( \text{Int} \) function in Eq.(8) with its rational argument. Mind double-logarithmic scale(s) for both panels of the figure.
Subsequently, Eq.(5) might be modified as follows:

$$W_D(E_T) \cong \Theta_M(E_T, T) \exp \left( \frac{-E_T}{k_B T} \right) \int_{M_0}^{M_M} \frac{1}{\Gamma(M+1)(Z_M)^{r^2}} \left[ \frac{2L_x L_y F(L_x, L_y, L_z)}{M^{r^1}(hc_1)^2} \right] M \, dM. \quad (9)$$

It is noteworthy, that left-hand half of the complex plane in Fig. 2(a) corresponds to negative \(\text{Re}\{\beta E_{mn}^{av}(E_T)\}\) quantities, which formally implies negative probability \([W_D(E_T)\text{ function(s)}]\) defined by Eq.(9). In order to overcome this problem, total contribution from ‘Matsubara correction(s)’ (expressed by \(\Theta_M(E_T, T)\) term – or Eq.(8)), is routinely evaluated via integration (summation) over poles of the Gibbs-Boltzmann term (with the purely interaction Hamiltonian!) in Eq.(5) in its complex time (or frequency) domain(s), following refs. [2, 3] and discussion just above herein.

Based on Eqs.(7, 8), which provide the physically meaningful number of poles of exponential term of Eq.(5), and evaluation results illustrated in Fig. 3(b), the dimensionless ‘Matsubara correction’ term \(\Theta_M(E_T, T)\) apparently might be approximated with a linear function of \(E_T\) at a given temperature \(T\):

$$\Theta_M(E_T, T) = \Theta_M^0(E_{mn}, T) * E_T, \quad (10)$$

where \(E_{mn}\) is a low limit of aggregate energy of the ensemble of acoustic phonons, imposed by presence of morphology (non-homogeneities), while \(\Theta_M^0(E_{mn}, T) = \Theta_M(E_{mn}, T)/E_{mn}\) is a dimensional (of eV\(^{-1}\)) and temperature-dependent factor; Eq.(10) valids at \((E_T \geq E_{mn})\) and \((E_{mn} \geq k_B T)\). Therefore, due to Eq.(15D) in ref. [1] and Eq.(10) above, the ‘partition function’, \(Z_M\), for the ‘isotropic version’ of the Eq.(9) reads:

$$Z_M = \Theta_M^0(E_{mn}, T)(k_B T)^{(2(M+2))} \left[\Gamma\left(2M+2, \left\{\frac{E_{mn}}{k_B T}\right\} \left(\left\{\frac{M k_B \theta_D}{k_B T}\right\}\right) \right] \left[\frac{2L_x L_y F(L_x, L_y, L_z)}{M^{r^1}(hc_1)^2} \right] M, \quad (11)$$

where \(\Gamma(m, z_0, z_1)\) is the ‘generalized incomplete Gamma function’ [5] with \(m = (2M + 2), z_0 = (E_{mn}/k_B T), z_1 = (M \cdot k_B \theta_D / (k_B T)) = M\theta_D / T\). It is noteworthy that the dimension of \(Z_M\) functions defined by Eq.(11) is still expressed in eVs; i.e., it remains unchanged as compared to its counterpart expressed by Eq.(15D) in ref. [1]: enlargement in the (rational) power of the \((k_B T)\) term is ‘compensated’ by appearance of the dimension \(\Theta_M^0(E_{mn}, T)\) one. Thus, though the dimensionless ‘Matsubara correction’ function \(\Theta_M(E_T, T)\) well exceeds \(10^3\) at \(T \approx 1\) K and \(E_T \geq 1\) eV [Fig. 3(b)], its ultimate effect on the \(W_D(E_T)\) distribution defined by the Eq.(9) would be eventually reduced due to ‘normalizing’ effect of the partition function \(Z_M\) (statistical sum). Similar ‘Matsubara correction’ might be also ‘embedded’ readily into an anisotropic version of the basic equation of GSM [1].

It is noteworthy, that depicted above ‘Matsubara correction’ and the basic equation(s) of the GSM are expressed herein predominantly using canonical (conservative) ‘first quantization’ formalism – instead of conceptually much more advanced and complicated frameworks of the Green Function (GF) and ‘second quantization’, implemented essentially in refs. [2-4] (see also references therein and second section of this article). Thus, the fundamental idea pioneered by T. Matsubara in ref. [2], evidently remains relevant even in such a case, and might be implemented readily within framework of the well-established conventional quantum statistical physics, which is still used widely nowadays in theory of crystalline and amorphous semiconductors and insulators. At the same time, aforementioned conservative ‘first quantization’ formalism allows significant simplifications of many basic physical concepts: e.g., the canonical ‘density matrix’ might be used instead of GFs and vector-like ‘time-ordering’ operators, while the single-particle basis phase space, one-dimensional distribution functions and ‘global’ density of states (DOS, either phononic or electronic) might substitute their essentially ‘local’, many-dimensional and many-particle counterpart(s) implemented customarily within frameworks of the GF formalism(s) [2-4], etc.; see also next section for more discussions. Moreover, the fundamental ‘Matsubara approach’ actually remains meaningful even within framework of entirely classical (non-quantized) statistical physics [8].

On the other hand, in spite of certain formal similarity among the path-integral-based formalism [9] and Matsubara one [2], the physical backgrounds of those formalisms and even their mathematical expressions are significantly different. Indeed, the real-time action (i.e. a time-dependent integral over a potential) in the canonical path integral formalism has to be replaced with imaginary-time integration within framework of Matsubara’s approach via (formal) implementation of ‘Wick rotation’, see ref. [7].
p.12. In general, both path-integral and Matsubara formalisms are equally applicable to bosonic and fermionic ensembles, though the path-integral usually oscillates far more strongly (with alterations in its sign!) as its argument vary, mainly due to necessity to comply with the Heisenberg’s uncertainty principle, and relatively low $h$ quantity (the dimensional $k_B T/h$ ratio is $\approx 1.309 \times 10^{11}$ at $T = 1$ K in appropriate SI units).

Therefore, the path-integral technique was widely implemented (e.g., refs. [9–11]) to relatively small (with the typical spatial extent of just very few Angstroms) parts of electronic sub-system, interacting with their ionic counterparts, while direct contributions from the quantized atomic vibrations (phonons) are usually ‘integrated out’ (eliminated) within the path-integral cum Lagrangian formalisms [9–11].

Introduced above in this section ‘Matsubara correction’ to the basic GSM equation(s) is expected to work well for polycrystalline semiconductors and insulators at a finite temperature. Furthermore, such ‘Matsubara correction’ is expected to remain relevant even at zero temperature for many amorphous solid semiconductors and insulators, where spatial atomic positions are commonly expected to be time-independent (static) – though generally affected by the ‘freeze-in’ temperature, established at the material formation (e.g., Eq.(37) on p.81 of ref. [1]). In other words, those atomic positions are still subjected to evolution in the ‘imaginary time’, though ‘traditional’ meaning [2] of the ‘imaginary time’ has to be amended, and rather linked to the (inverse) ‘freeze-in’ temperature – than to inverse actual absolute temperature of the material. It is noteworthy as well, that different versions of the GSM enable such kind of ‘Matsubara correction(s)’ readily, while many others well-known approaches to simulation on near-band-gap and intra-gap electronic DOS in disordered semiconductors (e.g., the semi-classical [12] and Halperin-Lax [13] ones) do not comprise the exponential Gibbs-Boltzmann term and might not be ‘corrected’ in this way.

At the same time, overall contribution even from non-normalized ‘Matsubara correction’ to the basic equations of the GSM [1] is expected to be relatively small for polycrystalline and spatially non-homogeneous amorphous semiconductors and insulators with typical sizes of non-homogeneities (grains) of the order of $\sim 1 \mu$m – or even sub-micrometer – (especially at elevated – e.g., ‘room’ – temperature $T$ and relatively low ($E_r < 1$ eV) aggregate energy of the phonon ensemble) as compared to effects caused by variation in the GSM model parameters, $r_1$ and $r_2$, in Eqs.(5, 9). Indeed, contribution from the main integrand term in Eqs.(5, 9) (located within square brackets in those equations) is $\approx -2.40 \times 10^8$ at $E_r = 1$ eV, $M = 1$, $r_1 = 1$ and $r_2 = 1$ for the $<100>$-oriented polycrystalline diamond with $L_x = L_y = L_z = 1 \mu$m, which exceeds even low-temperature ($T = 1$K) contribution from the $\Theta_{M}(E_r, T)$ term by a factor of $\approx 1.87 \times 10^6$, though this ratio apparently becomes much larger at elevated (room) temperatures. Similar ratios are expected as well for others polycrystalline and spatially non-homogeneous amorphous semiconductors and insulators, when dimensions $L_x$, $L_y$ and $L_z$ of their non-homogeneities are of $L_x, \approx L_y \approx L_z \approx 1 \mu$m. Thus, relatively small room-temperature ‘Matsubara corrections’ are generally expected for an ensemble of acoustic phonons confined within grains, columns, cones (etc.) of those polycrystalline and spatially non-homogeneous amorphous semiconductors and insulators at elevated temperatures. This statement might be verified independently: integration over the imaginary time is expected to yield just a partition function (for the aforementioned bosonic ensemble) at $\beta \to 0$ (or $T \to \infty$) limit(s), see details on p.13 of the ref. [7].

On the other hand, contribution from the ‘Matsubara correction’ function might be significant or even dominant for nano-structured semiconductors and insulators (e.g., when $L_x \approx L_y \approx L_z \approx 10$ nm), especially at low temperature and relatively high aggregate energy of the mixed states of the confined ensemble of acoustic phonons. Indeed, in such a case, contribution from the integrand term in Eqs.(5, 9, 11) is expected to be diminished by $\approx 6$ orders of the magnitude (as compared to the discussed above case of the $<100>$-oriented polycrystalline diamond), while contribution from the ‘Matsubara correction’ function $\Theta_{M}(E_r, T)$ remains unaffected by alterations in the sizes of the non-homogeneities (crystallites), and defined entirely by the aggregate energy of phononic ensemble and its (inverse) temperature.

Thus, following the fundamental idea pioneered by T. Matsubara in ref. [2], basic (and essentially static) equations (of original versions) of the GSM [1] might be ‘corrected’ in order to take into account effects of fluctuations in the absolute and/or ‘freeze-in’ temperature(s) of the ensemble of the confined acoustic phonons (via implementation of the dimensionless $\Theta_{M}(E_r, T)$ function, as it discussed above in this section), though such corrections are expected to be relatively small for polycrystalline and spatially non-homogeneous amorphous semiconductors and insulators with micrometer- and sub-micrometer sizes of non-homogeneities (grains), but might be significant or even dominant for their nano-structured counterparts. In addition, the model parameters, $r_1$ and $r_2$, of the GSM, are typically invariable (fixed) for the given set of simulations even though the $T$ and $E_r$ quantities may vary for this set [1], while the introduced above $\Theta_{M}(E_r, T)$ function is apparently temperature- and energy- dependent, see Fig. 3(a), (b). Furthermore, the static plane-wave basis of the GSM [1] might be expanded readily in the time domain.
4. Dynamic Expansion of Plane-wave Basis for GSM

In contrast to the original static version of the GSM and closely related to it static Born-Huang expansion (see Appendix A and Appendix B in ref. [1]), the single plane-wave eigenfunction \( \phi(\mathbf{r}, t) \) of the pure state (microstate) of the longitudinal Debye’s acoustic phonon with the ‘classical’ linear dispersion \( \omega_q = \mathbf{c} \mathbf{q} \) might be expanded readily both in time and spatial domains (i.e., formally represented within framework of Schrödinger’s picture of quantum mechanics with time-dependent eigenstates), and linked to its characteristic frequency \( \omega_q \) using analytical properties of the exponential (direct and inverse) Fourier transform(s) and well-known identities for Dirac’s \( \delta \)-function [6]:

\[
\phi(\mathbf{r}, t) \propto \exp \left[ -i \omega_q (t - t') \right] \exp \left[ -i \mathbf{q} (\mathbf{r} - \mathbf{r}') \right] = \delta(t - t') + \delta(\mathbf{r} - \mathbf{r}') \equiv \delta(t = t') + \delta(\mathbf{r} = \mathbf{r}'),
\]

where the quasi-wave-vector \( \mathbf{q} \) of the plane wave (pure state of acoustic phonon) defines spatial orientation of the plane-wave-function and its evolution in the space domain; see also Eq.(6) in the previous section. Thus, in contrast to the purely static wavefunctions of the GSM and canonical Born-Huang expansion [1], the plane-wave-function expressed by Eq.(6a) apparently becomes time-dependent (dynamic) due to its first term in the right-hand side(s), but retains spatial propagation direction of the plane wave due to the second one. Furthermore, it is easy to show that the given plane wave (eigenfunction) of the confined longitudinal Debye’s acoustic phonon apparently yields equal numbers of the poles (states), ‘located’ at \( t_n = (2n + 1)\pi/(2\omega_q) \) and \( \mathbf{r}_n = (2n + 1)\pi/(2\mathbf{q}) \) in the time and spatial domains (respectively); here \( n \) is an integer index, varying in the range: \( -\text{Int}(2LiLd) \leq n \leq \text{Int}(2LiLd) \), \( L = [(\varepsilon_r^2 + \varepsilon_l^2 + \varepsilon_y^2)/3]^1/2 \), while \( d \) is an average interatomic distance. This immediately implies that the crucially important (for generic solid state physics) concept of the phononic DOS implemented essentially in the original (static) versions of the GSM [1] might be retained even for the case of dynamic (time-dependent) expansion of the plane-wave basis of the GSM, though actual number of the ground phononic states corresponding to the given frequency \( \omega_q = \mathbf{c} \mathbf{q} \) has to be just multiplied by the factor of 2 as compared to its original static version. Furthermore, as it was discussed in the previous section (see also Eq.(6) therein and Eq.(6a) above), the dynamic (time-dependent) expansion of the plane-wave basis expressed by the latter equation allows one to establish a direct link among spectral characteristics of the GSM and those of the conventional equilibrium GF \( \hat{G}(\mathbf{r}_1, t_1, \mathbf{r}_2, t_2) \) with such basis (pure states), even though – in apparent distinction from the GSM – the \( \hat{G}(\mathbf{r}_1, t_1, \mathbf{r}_2, t_2) \) function is rather defined based on parameters of second-quantization operators acting on the time-dependent wave-functions (of the phononic ensemble), than based on actual dynamic characteristics of those wavefunctions (pure states of the ensemble) [2 – 4]. On the other hand, interrelations among key features of the GSM (even with the dynamic plane-wave basis) and those of the equilibrium Matsubara GF even with the same basis functions (pure states) are far less straightforward.

Indeed, based on the fundamental idea pioneered by T. Matsubara in ref. [2], the inverse temperature of the (bosonic or fermionic) ensemble has to be treated as an imaginary time, and the first (exponential, Gibbs-Boltzmann) and the rest (i.e., evaluated based on the DOS concept) terms of the ‘dynamic’ version of the GSM (see also Eq.(5) herein) should not be any more considered as truly independent ones, but become related intimately and affected by the system evolution on its complex time plane. It is noteworthy, that such approach to description of excitations of the bosonic or fermionic ensembles at a finite temperature is the genuine essence of the whole Matsubara statistics and the (equilibrium) Matsubara GF [2 – 4]. One of the most straightforward consequences of implementation of this ‘ideology’ to a quantum ensemble with plane-wave basis is that the spectral representation (direct Fourier transform) of the basis time-dependent plane-wave-function (e.g., pure state of acoustic phonon) now becomes a function of two frequencies: the real plane-wave circular frequency \( \omega_q \) (which characterize spatial oscillations of the plane waves, propagating freely in a direction defined by the quasi-wave vector \( \mathbf{q} \)) and the imaginary Matsubara frequencies \( \omega_n \) (which are rather related to inverse lifetime of those plane waves between two consecutive scattering events and/or their spatial decay) [6]:

\[
\Phi(\omega_n, \omega_q) = \frac{1}{i\omega_n + \omega_q} - \frac{1}{i\omega_n - \omega_q} = \frac{2\omega_q}{\omega_n^2 + \omega_q^2},
\]

with \( \omega_q = \mathbf{c} \mathbf{q} \). The latter equation is valid for bosonic excitations with plane-wave basis [4]. The inverse denominator of very last term in right-hand side of Eq.(12) is also known as spectral representation of
‘Matsubara thermal propagator’ [6]. Indeed, its poles (on the complex frequency plane) are apparently defined by the characteristic frequencies, \( \omega_n \) and \( \omega_{nr} \), of the dynamic plane-wave function. In contrast, spectral characteristics of both static and dynamic versions of the GSM are eventually defined by the poles in their spatial and complex time domains, which are, however, linked directly to real frequencies of (either static or dynamic) plane-wave basis functions (microstates), and imaginary (Matsubara) frequencies of the exponential (Gibbs-Boltzmann) term in Eq.(5). This similarity establishes an unambiguous link among spectral characteristics of the GSM and those of equilibrium GF formalism(s), even though traditional representation of the plane-wave Debye acoustic phonon(s) would be affected significantly within framework of Matsubara GF formalism due to strong temporal ‘confinement’ and decay of those phonons, imposed by existence of the imaginary Matsubara frequencies, and ‘truncating’ effect of the ‘time-ordering’ operator(s), which virtually impose considerable restrictions on lifetimes of those phonons. Instead, significant lifetime restriction of their mixed states within framework of the original GSM version(s) [1] is rather imposed by the combined effects of the freely propagating (within whole volume(s) of crystallites and non-homogeneities) plane waves (pure states) of Debye acoustic phonons – see Figs. 2D and 5D in Appendix D of ref. [1], as well as further discussion on this issue shortly below in this section.

As it is discussed briefly in the previous section (see also Fig. 2(a), (b) therein), in general, a whole (ultimately – infinite) set of Matsubara frequencies has to be taken into account at analysis of evolution of an ensemble on its complex frequency plane. However, summation even over an infinite set of the ‘Matsubara thermal propagators’ (with the conventional Matsubara frequencies, \( \omega_n \), evaluated based on the periodicity of Fourier expansion coefficients) often yields a finite (converging) expression [6]:

\[
\frac{1}{\hbar |\beta|} \sum_{n=-\infty}^{n=\infty} \frac{1}{\omega_n^2 + \omega_q^2} = \frac{1}{2\hbar \omega_q} \coth \left( \frac{\beta \hbar \omega_q}{2} \right) = \frac{1}{2\hbar \omega_q} \left[ 1 + 2n_{\text{BE}}(\hbar \omega_q) \right] \equiv n_{\text{eff}}(\hbar \omega_q),
\]

where the ‘conventional’ Matsubara frequencies \( \omega_n \) are numerated here by their integer (summation) index \( n \), while \( \coth(\beta \hbar \omega_q/2) \) denotes hyperbolic cotangent (of its argument), and \( n_{\text{BE}}(\hbar \omega_q) = \left[ \exp(\hbar \omega_q/k_B T) - 1 \right]^{-1} \) stands for the conventional Bose-Einstein occupation factor of the phononic state corresponding to the frequency \( \omega_q = \omega_{q0} \) [5]. This implies, that the right-hand side of Eq.(13) might be treated as an ‘effective’ occupation factor \( n_{\text{eff}}(\hbar \omega_q) \) of a ground Debye’s phononic state (with the plane-wave basis) of the (real and positive) frequency of \( \omega_q \). Since \( \omega_{(n=0)} = 0 \) for a bosonic ensemble [2–4] (see also Fig. 2(b) in the previous section), the sum(s) in the right-hand side of Eq.(13) might diverge at \( \omega_q \to 0 \) (i.e., in this limit, behaves similar to the spectral dependence \( n_{\text{BE}}(\hbar \omega_q) \) of the ‘standard’ Bose-Einstein occupation factor). However, even in polycrystalline and spatially non-homogeneous amorphous semiconductors and insulators with micrometer-sized crystallites (non-homogeneities), the \( \omega_q \) quantity is always non-zero due to effect of phonon confinement imposed by the limited spatial extent of those non-homogeneities. Therefore, the divergence in both \( n_{\text{eff}}(\hbar \omega_q) \) and \( n_{\text{BE}}(\hbar \omega_q) \) dependencies become avoidable even for those materials – not only for nano-structured semiconductors and insulators, where the phonon confinement effects are expected to be manifested in much more profound way (see, for instance, Fig. 4D in Appendix D of ref. [1]).

It is noteworthy that within framework of Matsubara GF formalism, summation over the whole (infinite) set of Matsubara states (poles of the complex frequency plan) amends an ‘effective’ occupation factor of conventional (ground) phononic states (see Eq.(13)), while Matsubara’s ‘correction’ (expansion) of the exponential (Gibbs-Boltzmann) occupation factor of multi-phonon states in Eq.(5) effectively enlarges number of those states for ensemble of confined acoustic phonons within the GSM framework. On the other hand, ‘Matsubara correction’ for the GSM formally amends an effective occupation factor of interacting states of ensemble of acoustic phonons at \( \omega_1 < 2 \), which deviates significantly from both Gibbs-Boltzmann and Bose-Einstein occupation factors (established for non-interacting bosonic ensembles), while the former one corresponds to \( r_1 = 2 \) and \( r_2 = 1 \) in the original version of GSM, depicted in ref. [1].

As it is shown in Fig. 4, spectral behavior of the room-temperature effective occupation \( n_{\text{eff}}(\hbar \omega_0) \) factor differs considerably from that of the standard Bose-Einstein one, \( n_{\text{BE}}(\hbar \omega_0) \), for ground states of ensemble of acoustic phonons of the diamond. In particular, it decays faster than the \( n_{\text{BE}}(\hbar \omega_0) \) one with the \( \hbar \omega_0 \) enlargement at relatively low phonon energies (\( \hbar \omega_0 < 20 \text{ meV} \)), but much slower than that at relatively high (\( \hbar \omega_0 > 50 \text{ meV} \)) those energies, Fig. 4. It is noteworthy, that in case of a real semiconductor and/or insulator (e.g., diamond), both dependencies remain meaningful only within the phonon energy range, limited by Debye energy, \( k_B T_0 \): conventional (ground) single-phonon states with higher energies simply do...
not exist in an equilibrium state of the ensemble of acoustic phonons! Thus, both dependencies plotted in Fig. 4 are truncated at the $k_B \theta_D$ energy.

Therefore, in order to evaluate statistical features of ensemble of acoustic phonons comprising excited and coherent states of those phonons, a many-particle counterpart of the conventional (global) single-phonon DOS had been introduced within the GSM framework; see Eqs.(1D, 2D) in Appendix D in ref. [1], and utilized in Eq.(5) of the previous section. Though total number of multi-phonon states available for an ensemble of M acoustic phonons is routinely evaluated based on symmetric tensor product of their single-particle Hilbert spaces [6, 7], the many-particle (though still one-dimensional and single-argument) DOS function is defined in ref. [1] based on a Cartesian product of the M single-particle phase spaces, and yields a number of available many-particle states corresponding to the given aggregate energy, $E_T$. That becomes viable because of the $E_T$ quantity is routinely expressed as a sum of eigenenergies $\hbar \omega_q$ of M individual (though equivalent) acoustic phonons. Thus, the multi-phonon statistics introduced within the GSM framework replicates entirely conventional statistical approach: it comprises one-dimensional many-particle DOS function, and the standard Gibbs-Boltzmann exponential occupation factor for those many-particle states. The essentially same statistical approach apparently remains valid as well for any single phonon of the ensemble: its total number of available global states is defined by volume of the single-phonon phase space expressed in $\hbar^3$ units (see section 2.3 and Appendix D in ref. [1]), while the Gibbs-Boltzmann occupation factor of a single-phonon state is defined by its energy $\hbar \omega_q$ ($E_{\min} \leq \hbar \omega_q \leq k_B \theta_D$), and the temperature $T$ of the ensemble. Furthermore, in principle, the concept of global many-particle phononic DOS, introduced within the GSM framework [1], allows one to retain even quasi-wave vectors $q$ of all individual acoustic phonons of the ensemble, though (as it is discussed in details shortly below) an aggregate wave vector of aforementioned excited (and even coherent!) states rather becomes ‘ill-defined’.

Thus, spectral characteristics of excited and coherent states of longitudinal acoustic phonons are always evaluated based on eigenenergies of single Debye acoustic phonons, which allows one to retain traditional concept of the global phononic DOS for those individual phonons and introduced in ref. [1] its global many-particle counterpart, as well as ensure that basic quasi-wave vectors $q$ of individual phonons are well-defined and always located within the first phononic Brillouin Zone (BZ). In other words, excited and coherent states are always composed as mixed quantum states of the ensemble of acoustic phonons within the GSM framework, while quasi-wave vector of those states becomes ‘ill-defined’ quantity – since

**FIG. 4** (color online). The room-temperature spectral dependencies of the ‘standard’ Bose-Einstein occupation factor $n_{BE}(\hbar \omega_q)$ and its ‘effective’ counterpart $n_{eff}(\hbar \omega_q)$, defined by Eq.(13). Both dependencies are evaluated for ground single-particle states of Debye acoustic phonons of the diamond with its Debye energy of $k_B \theta_D = 193.0$ meV ($\theta_D = 2240$ K), indicated in the figure with the vertical dashed line. See further details in the main text.
their ‘aggregate’ quasi-wave vector is often expected to exceed significantly the edge of the first phononic BZ. Moreover, typical spatial extent of excited states is well comparable with an inter-atomic distance \( d \) of a semiconductor (insulator): see Figs. 3D, 6D in Appendix D of ref. [1]. Thus, this spatial extent is (many) orders of the magnitude shorter than typical sizes of crystallites (non-homogeneities) in polycrystalline and spatially non-homogeneous amorphous semiconductors and insulators. Hence, such excited (mixed) states are essentially localized, and could hardly be characterized by any meaningful wave-vector, even though longitudinal acoustic plane waves (pure states of Debye phonons) as well as corresponding coherent states might propagate within the whole volume of those non-homogeneities without significant disruption [1], and are described by their well-defined (for the pure states only!) vectors \( \mathbf{q} \), see Eq.(6a).

In contrast, Klauder’s bosonic coherent states \( \langle \mathbf{N}_c \rangle \) are apparently well-defined for photonic excitations in vacuum, though they are usually characterized by a quasi-wave vector \( \mathbf{q}_c \), located well outside of the first BZ of the (longitudinal acoustic) phonons. Moreover, based on the ‘classic’ dispersion relation, \( \omega = c \mathbf{q}_c \), the phonon energy \( \hbar \omega \) would routinely exceed its upper physical limit – the Debye’s energy \( (K_\text{B} T) \) – defined for the ground states of acoustic phonons; see also comments to Eq.(5) and Fig. 4 above. All these apparently imply that the \( \mathbf{q}_c \) quantity becomes ‘ill-defined’ as well even for Klauder’s coherent phononic states, and so-called Umklapp processes have to be taken into account at a quantitative description of electron interactions with those phononic states and phonon-phonon interactions. Thus, though similar to the coherent states of the GSM, Klauder’s phononic coherent states might be associated as well with propagating thermal plane waves in solids, they are, however, should not be identified as pure states (microstates) of the phononic ensemble.

It is noteworthy as well, that the set of (dimensionless in such a case) Matsubara frequencies is limited (truncated) for the GSM – since it is defined based on the periodicity condition of the exponential term in Eq.(5); see also brief discussion in the previous section, and Eqs.(7, 8) therein. Consequently, within the GSM framework, spectral density of acoustic phonons [6] (which generalizes traditional concept of conventional (global) one-dimensional phononic DOS spectrum – since the latter one is not applicable directly within framework of the GF formalism) with the dynamic plane-wave basis might be linked in such a case directly to the dynamic DOS function, multiplied by the \( \Theta_M(E_T/M, T) \) term. Thus, a dynamic counterpart of Eq.(9) now reads:

\[
W_D(E_T) \equiv \exp \left( -\frac{E_T}{K_B T} \right) \int_0^\infty \frac{1}{M+1}(M) \left( \frac{4 \mathbf{L}_x \mathbf{L}_y \mathbf{F}(\mathbf{L}_x, \mathbf{L}_y, \mathbf{L}_z) \Theta_M(E_T/M, T) E_T^2}{M^{r_1}(h\mathbf{c}_T)^2} \right) dM .
\] (14)

The ‘partition function’ \( Z_M \) for the Eq.(9), expressed by Eq.(11) above, now has to be amended as well:

\[
Z_M = (K_B T)^{2(M+1)} \Gamma \left[ \left( 2M + 1 \right), \left( E_{\text{min}} k_B T \right), \left( M k_B T \right) \right] \left[ \frac{4 \mathbf{L}_x \mathbf{L}_y \mathbf{F}(\mathbf{L}_x, \mathbf{L}_y, \mathbf{L}_z) \Theta_M(E_T/M, T)}{M^{r_1}(h\mathbf{c}_T)^2} \right] .
\] (15)

Again, in the \( T \to \infty \) limit, Eqs.(14, 15) are expected to coincide with their ‘conservative’ counterparts expressed for this case by the Eqs.(26a, 15D) in ref. [1] (respectively). In particular, Eq.(15) would yield the conventional ‘partition function’ at \( \beta \to 0 \) (\( T \to \infty \)) [7], see also Fig. 3(b) in the previous section. The Eq.(14) allows one to re-define the GSM parameter \( r_1 \) as the energy–temperature–dependent one: \( r_1(E_T, T, M) = 2 - \ln(\Theta_M(E_T/M, T))/\ln(M) \); here \( \ln(x) \) denotes the ‘natural’ logarithm of \( x \). Similarly, the \( r_1 \) counterpart for Eq.(9) in the previous section reads: \( r_1(E_T, T, M) = 2 - \ln(\Theta_M(E_T, T))/\ln(M) \). Both latter expressions apparently yield: \( r_1(E_T, T, M) = 2 - \Theta_M(E_T, T) = 1 \), though diverge at \( M = 1 \). On the other hand, the \( \Theta_M(E_T, T) \) function depends, in turn, on the interaction Hamiltonian of the GSM, defined by Eq.(7) in the previous section, and it is affected decisively by variations in the GSM parameter, \( r_1 \); see Fig. 1(a), (b) and comments to it above.

Thus, the essentially dynamic formalism, depicted above in this section, might be implemented readily for quantitative evaluation of statistical properties of ensembles of acoustic phonons in polycrystalline and even spatially non-homogeneous amorphous semiconductors and related to them electronic and optical characteristics of those materials at a finite temperature, though original static plane-wave basis might be probably retained for amorphous semiconductors at zero temperature. This also expands further scope of the GSM, establishes its intimate relationship with the equilibrium conventional and Matsubara GFs, and inspires its direct implementation to the nano-structured semiconductors and insulators.
5. Conclusions

In summary, the GSM presented in ref. [1] might be treated as a kind of ‘conservative’ (i.e., essentially static and based on the canonical ‘first quantization’) counterpart to the well-known quantum Matsubara statistics (and closely related to it equilibrium conventional and Matsubara’s Green Functions formalisms [2 – 4]) for the particular cases of ensemble(s) of acoustic phonons confined within polycrystalline and spatially non-homogeneous amorphous semiconductors (insulators) with micrometer- and sub-micrometer sizes of non-homogeneities (crystallites), though the GSM apparently is not applicable directly to the ensemble of fermions and essentially uses static Debye’s plane wavefunctions basis (pure quantum states), while other convenient sets of basis functions (e.g., time-dependent eigenfunctions of the quantum harmonic oscillator, QHO) might be used as well within the generic framework of GF formalism(s) [3].

On the other hand, the static plane wave-functions basis of Debye acoustic phonons implemented within the GSM [1] allows one to use effectively advantages of the Christoffel Matrix formalism (see Appendix C in ref. [1]), and those of conventional global phononic (and/or electronic) DOS concept, inspires its straightforward extension to the many-particle DOS of ensemble of Debye acoustic phonons (see Appendix D in ref. [1]), simplify considerably final equation(s) of the GSM, incorporate it naturally into conventional framework(s) of the solid state and statistical physics, as well as to take into account long-range (e.g., coherent, morphological) and anisotropic effects (if any) in polycrystalline and spatially non-homogeneous amorphous semiconductors and insulators [1], while routine implementation of others sets of the basis wave functions (e.g., QHO eigenfunctions) might not allow to utilize aforementioned advantages [3], and apparently would yield in (much) more time- and resource-demanding computations.

Moreover, mentioned above long-range and morphological effects could hardly be expected to be taken into account appropriately within framework of GF formalism even at implementation of the plane-wave basis (eigenfunctions); e.g. those of the ensemble of Debye acoustic phonons. That is mainly due to strong temporal ‘confinement’ and decay of those phonons, imposed by presence of the imaginary Matsubara frequencies in the spectrum of this ensemble, and ‘truncating’ effect of the ‘time-ordering’ operator(s). Both aforesaid effects virtually restrict nominal spatial propagation ranges and lifetimes of those phonons, and make questionable an implication of the conventional concepts of the global phononic and electronic DOS within framework of GF formalism. On the other hand, anisotropic effects in atomic (phononic) sub-system of crystalline semiconductors and insulators still might be taken into account within framework of Matsubara GF formalism on condition of dominance of Debye acoustic phonons with a linear dispersion in those solids. Indeed, both transverse and longitudinal sound velocities are generally affected by Miller indexes of a crystalline solid (see also Table 1 and Appendix C in ref. [1] for details), and linked directly to the frequencies of appropriate Debye acoustic phonons, as well as to real frequencies of corresponding ‘Matsubara thermal propagator’ [6].

Furthermore, the basis and scope of the GSM might be expanded even further based on fundamental ideas, pioneered by Takeo Matsubara in ref. [2]. In particular, the essentially static set of the basis wavefunctions of the original version of the GSM [1] might be expanded readily using the time-dependent (dynamic) plane-wave basis for pure states (microstates) of Debye acoustic phonons. Importantly, that such dynamic expansion allows one to retain almost entirely vital features of the conventional (static) phononic and electronic DOS concept (essentially used in original versions of the GSM [1]) and key structures of its basic equations. Furthermore, such kind of dynamic expansion allows one to establish physically unambiguous link among spectral characteristics of the (original, static, and modified, dynamic, versions of) GSM and those of equilibrium conventional and Matsubara Green Functions. In addition, ‘Matsubara correction’ to the Gibbs-Boltzmann occupation factor (of the basic equations) of the GSM routinely yields ‘supplementary’ (Matsubara) states for the ensemble of acoustic phonons with both static and/or dynamic plane-wave basis. However, contribution(s) from those states become(s) significant only for nano-structured semiconductors and insulators. At the same time, based on the aforementioned ‘Matsubara correction’, the fixed model parameters r1 and r2 (which are linked closely both to the total number of available states in the phase space of a single acoustic phonon, and intensity of phonon-phonon interactions in the original version of the GSM [1]) might be re-defined readily as the energy- and temperature-dependent ones, following the ‘Matsubara style’.

All these validate rigorous physical background for the basic ideas and principal equations of (both original, static, and modified, dynamic, versions of) the GSM, and inspire its direct implementation to appropriate quantitative descriptions of statistical characteristics of phononic excitations with the plane-wave basis in nano-structured semiconductors and insulators as well as to their near-band-gap and intra-gap electronic and optical spectra.
The ‘Generalized Skettrup Model’ and Matsubara Statistics

References


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